

Appl. No. : **10/809,983**
Filed : **March 26, 2004**

AMENDMENTS TO THE SPECIFICATION

Please replace the first paragraph starting on page 1 line 4 with the following amended paragraph:

This application is a continuation application of copending U.S. Patent Application No. 10/366,292, entitled "PULSED WRITE TECHNIQUES FOR MAGNETO-RESISTIVE MEMORIES," filed on February 13, 2003, now U.S. Patent No. 6,724,654 issued on April 20, 2004 [Attorney Docket: MICRON.215DV2C1], which is a continuation application of U.S. Patent Application No. 10/174,215, filed on June 17, 2002, now U.S. Patent No. 6,532,168 issued on March 11, 2003 [MICRON.215DV2], which was a divisional of U.S. Patent Application No. 09/638,637, filed on August 14, 2000, now U.S. Patent No. 6,493,259 issued on December 10, 2002 [MICRON.215A], the entireties of which are hereby incorporated by reference herein.